DESCRIPTION

The SM220A~SM2200A are available in SMA package.

ORDERING INFORMATION

Package Type Part Number					
SMA	SM220A				
	SM240A				
	SM260A				
	SM280A				
	SM2100A				
	SM2120A				
	SM2150A				
	SM2200A				
Note	5,000pcs/Reel				
AiT provides all RoHS Compliant Products					

FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Available in SMA package

MECHANICAL DATA

Case: SMA

Terminals: Solderable per MIL-STD-750,

Method 2026

Approx. Weight: 60mg / 0.0021oz

PIN DESCRIPTION



ABSOLUTE MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter Parameter		Symbol	SM 220A	SM 240A	SM 260A	SM 280A	SM 2100A	SM 2120A	SM 2150A	SM 2200A	Unit
Maximum Repetitive Peak Reve	V _{RRM}	20	40	60	80	100	120	150	200	V	
Maximum RMS Voltage	V _{RMS}	14	28	42	56	70	84	105	140	V	
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V	
Maximum Average Forward Rectified Current		I _{F(AV)}	2.0						Α		
Peak Forward Surge Current,8.3ms Single Half Sine-wave Superimposed		I _{FSM}	50 40					Α			
on Rated Load (JEDEC method) Max Instantaneous Forward Voltage at 2A		V _F	0.	55	0.	0.70 0		.85 0.9		95	V
Maximum DC Reverse Current at Rated DC Reverse Voltage	T _A =25°C T _A =100°C	I _R	0.5 0.3 5 3			mA					
Typical Junction CapacitanceNOTE1		CJ	22	220 80			pF				
Typical thermal Resistance ^{NOTE2}		Reja	80					°C/W			
Operating Junction Temperature Range		TJ	-55 to +125					°C			
Storage Temperature Range		T _{stg}	-55 to +150						°C		

NOTE1: Measured at 1MHz and applied reverse voltage of 4 V D.C.

NOTE2: P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

SCHOTTKY DIODE REVERSE VOLTAGE 20 TO 200V FORWARD CURRENT 2.0A

TYPICAL PERFORMANCE CHARACTERISTICS

Figure. 1 Forward Current Derating Curve

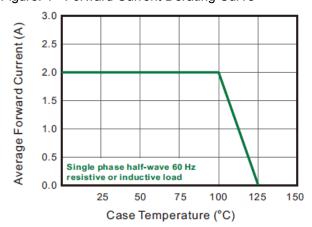


Figure. 3 Typical Forward Characteristic

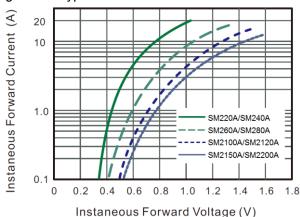


Figure. 5 Maximum Non-Repetitive Peak

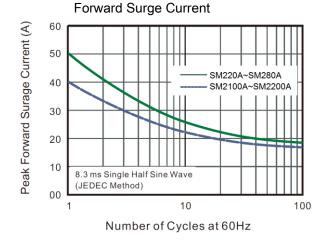


Figure. 2 Typical Reverse Characteristics

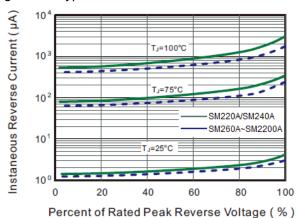


Figure. 4 Typical Junction Capacitance

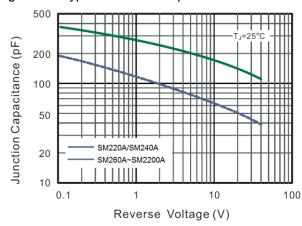
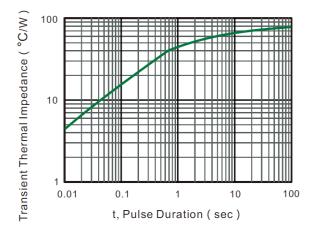
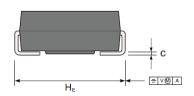


Figure. 6 Typical Transient Thermal Impedance

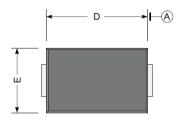


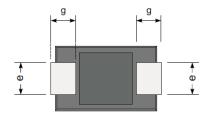
PACKAGE INFORMATION

Dimension in SMA Package (Unit: mm)

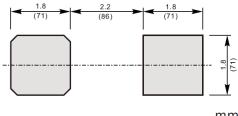








The recommended mounting pad size



Unit: $\frac{mm}{(mil)}$

UNIT		Α	D	Е	HE	С	е	g
mm	max	2.2	4.83	2.9	5.4	0.31	1.7	1.5
	min	1.9	4.32	2.3	4.7	0.12	1.2	0.9
mil	max	87	190	114	213	12	67	59
	min	75	170	91	185	5	47	35



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